MMSD71RKT1

Switching Diode

The switching diode has the following features:

Features

- SOD-123 Surface Mount Package
- High Breakdown Voltage
- Fast Speed Switching Time
- Pb-Free Package is Available



Rating	Symbol	Value	Unit
Continuous Reverse Voltage	V_R	80	Vdc
Peak Forward Current	I _F	200	mAdc
Peak Forward Surge Current	I _{FM(surge)}	500	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR–5 Board (Note1) T _A = 25°C Derate above 25°C	P _D	425 3.4	mW mW/°C
Thermal Resistance Junction-to-Ambient	$R_{\theta JA}$	290	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	–55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-5 = 1.0oz Cu, 1.0inz pad



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SOD-123 CASE 425 STYLE 1

MARKING DIAGRAM



6S = Device Code M = Date Code

= Pb-Free Package(Note: Microdot may be in either location)

ORDERING INFORMATION

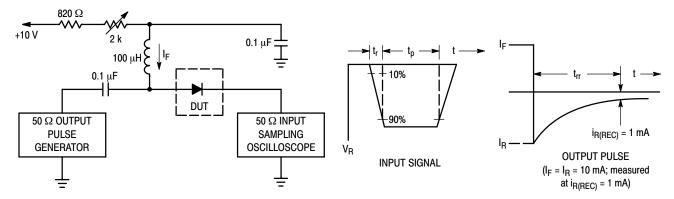
Device	Package	Shipping [†]
MMSD71RKT1	SOD-123	3000 / Tape & Reel
MMSD71RKT1G	SOD-123 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MMSD71RKT1

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS		•		
Reverse Breakdown Voltage (I _{BR} = 100 μAdc)	V _(BR)	80	_	Vdc
Reverse Voltage Leakage Current (V _R = 80 Vdc)	I _R	-	500	nAdc
Forward Voltage (I _F = 100 mAdc)	V _F	_	1200	mVdc
Diode Capacitance (V _R = 0.5 Vdc, f = 1.0 MHz)	C _D	_	2.0	pF
Reverse Recovery Time $(I_F = I_R = 10 \text{ mAdc})$ (Figure 1)	t _{rr}	-	4.0	ns

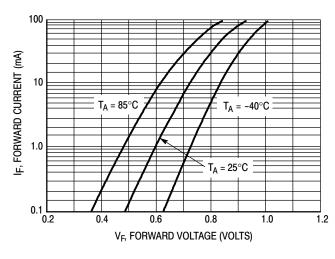


Notes: 1. A 2.0 k Ω variable resistor adjusted for a Forward Current (I_F) of 10 mA.

- 2. Input pulse is adjusted so $I_{R(peak)}$ is equal to 10 mA.
- 3. t_p » t_{rr}

Figure 1. Recovery Time Equivalent Test Circuit

MMSD71RKT1



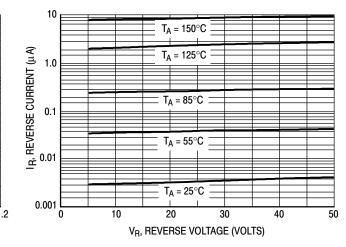


Figure 2. Forward Voltage

Figure 3. Leakage Current

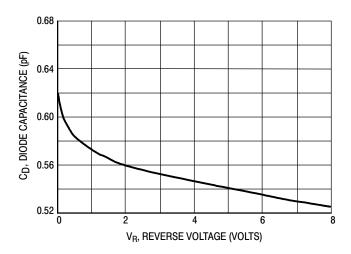


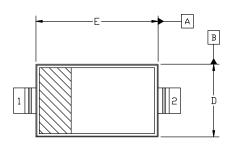
Figure 4. Capacitance



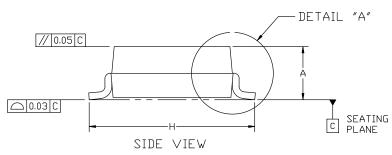


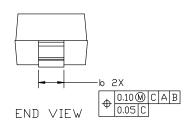
SOD-123 2-LEAD, 1.60x2.69x1.16 CASE 425 ISSUE H

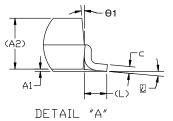
DATE 29 FEB 2024



TOP VIEW



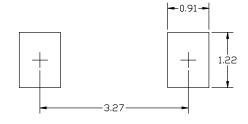




NOTES:

- . DIMENSION AND TOLERANCING PER ASME Y14.5M, 2018
- 2. CONTROLLING DIMENSION: MILLIMETERS

	MILLIMETER			
DIM	MIN.	N□M.	MAX.	
А	0.94	1.17	1.35	
A1	0.00	0.05	0.10	
A2	1.16 REF.			
b	0.51	0.61	0.71	
C	_	_	0.15	
D	1.40	1.60	1.80	
E	2.54	2.69	2.84	
Н	3.56	3.68	3,86	
L	0.25 REF.			
<u>S</u>	0°		10°	
θ1	0°		10°	



RECOMMENDED MOUNTING FOOTPRINT *For additional information on or Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference manual SDLDERRM/D.

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1: PIN 1. CATHODE

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DESCRIPTION:	SOD-123 2-LEAD, 1.60x2.69x1.16		PAGE 1 OF 1	

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